

DATASHEET

Description

The 9DBU0841 is a member of IDT's 1.5V Ultra-Low-Power (ULP) PCIe family. It has integrated output terminations providing Zo=100 Ω for direct connection to 100 Ω transmission lines. The device has 8 output enables for clock management and 3 selectable SMBus addresses.

Recommended Application

1.5V PCIe Gen1-2-3 Zero Delay/Fanout Buffer (ZDB/FOB)

Output Features

• 8 - 1-167MHz Low-Power (LP) HCSL DIF pairs $w/ZO=100\Omega$

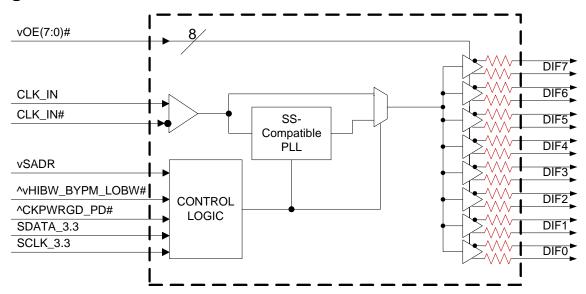
Key Specifications

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew < 80ps
- DIF phase jitter is PCIe Gen1-2-3 compliant
- Very low additive phase jitter in bypass mode

Features/Benefits

- Direct connection to 100Ω transmission lines; saves 32 resistors compared to standard HCSL outputs
- 53mW typical power consumption in PLL mode; eliminates thermal concerns
- Outputs can optionally be supplied from any voltage between 1.05 and 1.5V; maximum power savings
- Spread Spectrum (SS) compatible; allows SS for EMI reduction
- OE# pins; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- Spread Spectrum tolerant; allows reduction of EMI
- SMBus-selectable features; optimize signal integrity to application
 - slew rate for each output
 - differential output amplitude
- Pin/SMBus selectable PLL bandwidth and PLL Bypass; optimize PLL to application
- Outputs blocked until PLL is locked; clean system start-up
- Device contains default configuration; SMBus interface not required for device control
- Three selectable SMBus addresses; multiple devices can easily share an SMBus segment
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 48-pin 6x6mm VFQFPN; minimal board space

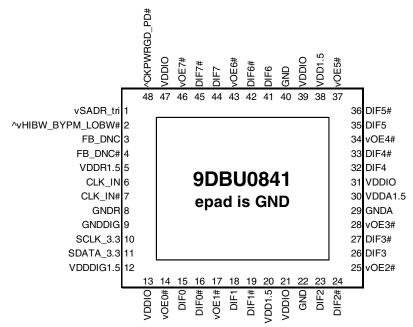
Block Diagram



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Pin Configuration



48-pin VFQFPN, 6x6 mm, 0.4mm pitch

- ^v prefix indicates internal 120KOhm pull up AND pull down resistor (biased to VDD/2)
- v prefix indicates internal 120KOhm pull down resistor
- ^ prefix indicates internal 120KOhm pull up resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of	0	1101011	X
CKPWRGD PD#	M	1101100	X
CKFWKGD_FD#	1	1101101	x

Power Management Table

CKPWRGD_PD#	CLK_IN	SMBus OEx# Pin		DIF	PLL	
	CLK_IN	OEx bit	OLX# FIII	True O/P	Comp. O/P	FLL
0	X	Х	X	Low	Low	Off
1	Running	0	X	Low	Low	On ¹
1	Running	1	0	Running	Running	On ¹
1	Running	1	1	Low	Low	On ¹

^{1.} If Bypass mode is selected, the PLL will be off, and outputs will be running.

Power Connections

Pin Number			Description
VDD	VDDIO	GND	Description
			Input
5		8	receiver
12		9	Digital Power
20, 31, 38	13, 21, 31, 39, 47	22, 29, 40	DIF outputs
30		29	PLL Analog

Note: epad on this device is not electrically connected to the die. It should be connected to ground for best thermal performance.

PLL Operating Mode

HiBW_BypM_LoBW#	MODE	Byte1 [7:6] Readback	Byte1 [4:3] Control
0	PLL Lo BW	00	00
M	Bypass	01	01
1	PLL Hi RW	11	11



Pin Descriptions

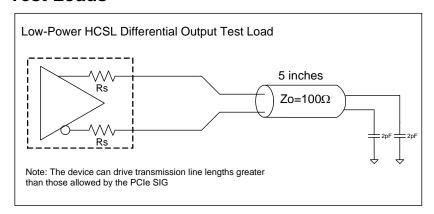
PIN#	PIN NAME	TYPE	DESCRIPTION
1	vSADR tri	LATCHED	Tri-level latch to select SMBus Address. See SMBus Address Selection Table.
	VOADh_III	IN	TIT-level later to select Sivibus Address. See Sivibus Address Selection Table.
2	^vHIBW_BYPM_LOBW#	LATCHED	Trilevel input to select High BW, Bypass or Low BW mode.
	*VIIIDVV_DII IVI_LODVV#	IN	See PLL Operating Mode Table for Details.
3	FB_DNC	DNC	True clock of differential feedback. The feedback output and feedback input are
	טווט_ט ו	DIVO	connected internally on this pin. Do not connect anything to this pin.
4	ED DNO#	DNC	Complement clock of differential feedback. The feedback output and feedback
4	FB_DNC#	DNC	input are connected internally on this pin. Do not connect anything to this pin.
	VDDD4 5	DIAID	1.5V power for differential input clock (receiver). This VDD should be treated as
5	VDDR1.5	PWR	an Analog power rail and filtered appropriately.
6	CLK_IN	IN	True Input for differential reference clock.
7	CLK_IN#	IN	Complementary Input for differential reference clock.
8	GNDR	GND	Analog Ground pin for the differential input (receiver)
9	GNDDIG	GND	Ground pin for digital circuitry
10	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	VDDDIG1.5	PWR	1.5V digital power (dirty power)
13	VDDIO	PWR	Power supply for differential outputs
14	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down.
14	VOEU#	IIN	1 =disable outputs, 0 = enable outputs
15	DIF0	OUT	Differential true clock output
16	DIF0#	OUT	Differential Complementary clock output
17	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down.
17	VOL 1#	1111	1 =disable outputs, 0 = enable outputs
18	DIF1	OUT	Differential true clock output
19	DIF1#	OUT	Differential Complementary clock output
20	VDD1.5	PWR	Power supply, nominally 1.5V
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin.
23	DIF2	OUT	Differential true clock output
24	DIF2#	OUT	Differential Complementary clock output
25	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down.
			1 =disable outputs, 0 = enable outputs
26	DIF3	OUT	Differential true clock output
27	DIF3#	OUT	Differential Complementary clock output
28	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down.
			1 =disable outputs, 0 = enable outputs
29	GNDA	GND	Ground pin for the PLL core.
30	VDDA1.5	PWR	1.5V power for the PLL core.
31	VDDIO	PWR	Power supply for differential outputs
32	DIF4	OUT	Differential true clock output
33	DIF4#	OUT	Differential Complementary clock output
34	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down.
			1 =disable outputs, 0 = enable outputs
35	DIF5	OUT	Differential true clock output
36	DIF5#	OUT	Differential Complementary clock output
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down.
			1 =disable outputs, 0 = enable outputs
38	VDD1.5	PWR	Power supply, nominally 1.5V
39	VDDIO	PWR	Power supply for differential outputs
40	GND	GND	Ground pin.



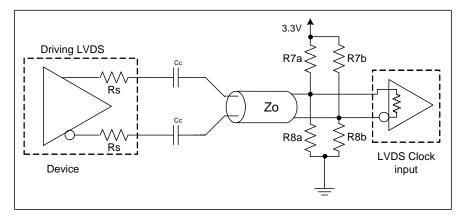
Pin Descriptions (cont.)

PIN#	PIN NAME	TYPE	DESCRIPTION
41	DIF6	OUT	Differential true clock output
42	DIF6#	OUT	Differential Complementary clock output
43	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.
40	VOLO#	111	1 =disable outputs, 0 = enable outputs
44	DIF7	OUT	Differential true clock output
45	DIF7#	OUT	Differential Complementary clock output
46	vOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.
40	VOL7#	IIN	1 =disable outputs, 0 = enable outputs
47	VDDIO	PWR	Power supply for differential outputs
			Input notifies device to sample latched inputs and start up on first high
48	^CKPWRGD_PD#	IN	assertion. Low enters Power Down Mode, subsequent high assertions exit
			Power Down Mode. This pin has internal pull-up resistor.
49	EPAD	GND	Connect ePAD to ground.

Test Loads



Driving LVDS



Driving LVDS inputs

Briving Ev Bo inputo							
	,						
	Receiver has Receiver does not						
Component	termination	have termination	Note				
R7a, R7b	10K ohm	140 ohm					
R8a, R8b	5.6K ohm	75 ohm					
Cc	0.1 uF	0.1 uF					
Vcm	1.2 volts	1.2 volts					



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBU0841. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx		-0.5		2	V	1,2
Input Voltage	V_{IN}		-0.5		V _{DD} +0.5	V	1,3
Input High Voltage, SMBus	V_{IHSMB}	SMBus clock and data pins			3.3	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Clock Input Parameters

TA = T_{AMR} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES		
Input Common Mode Voltage - DIF_IN	V _{COM}	Common Mode Input Voltage	200		725	mV	1		
Input Swing - DIF_IN	V _{SWING}	Differential value	300		1450	mV	1		
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2		
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA			
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45	50	55	%	1		
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		150	ps	1		

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.0V.

² Slew rate measured through +/-75mV window centered around differential zero



Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.425	1.5	1.575	V	
Output Supply Voltage	VDDIO	Supply voltage for Low Power HCSL Outputs	0.95	1.05-1.5	1.575	V	
Ambient Operating	т	Commmercial range	0	25	70	°C	1
Temperature	T_{AMB}	Industrial range	-40	25	85	°C	1
Input High Voltage	V_{IH}	Single-ended inputs, except SMBus	0.75 V _{DD}		$V_{DD} + 0.3$	V	
Input Mid Voltage	V_{IM}	Single-ended tri-level inputs ('_tri' suffix)	$0.4~V_{DD}$		$0.6~V_{DD}$	V	
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus	-0.3		0.25 V _{DD}	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Inner t Correspond		Single-ended inputs					
Input Current	I _{INP}	$V_{IN} = 0 \text{ V}$; Inputs with internal pull-up resistors	-200		200	uA	
		$V_{IN} = VDD$; Inputs with internal pull-down resistors					
Innut Francisco	F _{ibyp}	Bypass mode	1		167	MHz	2
Input Frequency	F_{ipII}	100MHz PLL mode	20	100.00	110	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,5
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization		From V _{DD} Power-Up and after input clock			1	mo	1,2
Cik Stabilization	T _{STAB}	stabilization or de-assertion of PD# to 1st clock		'	ms	1,2	
Input SS Modulation	f _{MODINPCle}	Allowable Frequency for PCIe Applications	30		33	kHz	
Frequency PCIe	MODINPCIe	(Triangular Modulation)			00	KIIZ	
Input SS Modulation	f _{MODIN}	Allowable Frequency for non-PCIe Applications	0		66	kHz	
Frequency non-PCle	WODIN	(Triangular Modulation)					
OE# Latency	t _{LATOE#}	DIF start after OE# assertion	1		3	clocks	1,3
		DIF stop after OE# deassertion DIF output enable after					
Tdrive_PD#	t _{DRVPD}	PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	V _{ILSMB}	у			0.6	V	
SMBus Input High Voltage	V _{IHSMB}	$V_{DDSMB} = 3.3V$, see note 4 for $V_{DDSMB} < 3.3V$	2.1		3.3	V	4
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V _{DDSMB}	Bus Voltage	1.425		3.3	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	6
Frequency	- INIWYOINID				.50	12_	

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

 $^{^4}$ For $V_{\text{DDSMB}} < 3.3 V, \ V_{\text{IHSMB}} >= 0.8 x V_{\text{DDSMB}}$

⁵DIF_IN input

⁶The differential input clock must be running for the SMBus to be active



Electrical Characteristics-DIF Low-Power HCSL Outputs

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AIVID,I-I-7	·	<u> </u>					
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	1	2.4	3.5	V/ns	1,2,3
Siew fate	dV/dt	Scope averaging on, slow setting	0.7	1.7	2.5	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		9	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	630	750	850	mV	7
Voltage Low	V_{LOW}	averaging on)		26	150	""	7
Max Voltage	Vmax	Measurement on single ended signal using		763	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	22		IIIV	7
Vswing	Vswing	Scope averaging off	300	1448		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	390	550	mV	1,5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		11	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Current Consumption

TA = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	I _{DDA}	VDDA+VDDR, PLL Mode, @100MHz		11	15	mA	
Operating Supply Current	I _{DD}	VDD, All outputs active @100MHz		6	9	mA	
	I _{DDIO}	VDDIO, All outputs active @100MHz		28	35	mA	
Powerdown Current	I _{DDAPD}	VDDA+VDDR, CKPWRGD_PD#=0		0.5	1	mA	2
	I _{DDPD}	VDDx, CKPWRGD_PD#=0		0.6	1	mA	2
	I _{DDIOPD}	VDDIO, CKPWRGD_PD#=0		0.003	0.01	mA	2

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² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.

² Input clock stopped.



Electrical Characteristics-Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
PLL Bandwidth	BW	-3dB point in High BW Mode (100MHz)	2.3	3.6	4.7	MHz	1,5
FLL Balldwidth	DVV	-3dB point in Low BW Mode (100MHz)	B point in High BW Mode (100MHz) 2.3 3.6 4.7 MHz B point in Low BW Mode (100MHz) 1 1.6 2.5 MHz Peak Pass band Gain (100MHz) 1.3 2.5 dB Measured differentially, PLL Mode 45 50 55 %	MHz	1,5		
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain (100MHz)		1.3	2.5	dB	1
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode			%	1,3	
Skew, Input to Output	t _{pdBYP}	Bypass Mode, $V_T = 50\%$	3400	4301	5200	ps	1
Skew, input to Output	t _{pdPLL}	PLL Mode V _T = 50%	0	50	4.7 MHz 2.5 MHz 2.5 dB 55 % 0 % 5200 ps 150 ps 75 ps	1,4	
Skew, Output to Output	t _{sk3}	V _T = 50%		37	75	ps	1,4
Jitter, Cycle to cycle	+.	PLL mode		24	50	ps	1,2
Jitter, Cycle to Cycle	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		0.1	10	ps	1,2

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Electrical Characteristics-Phase Jitter Parameters

TA = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

						INDUSTRY		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		30	58	86	ps (p-p)	1,2,3,5
PARAMETER Phase Jitter, PLL Mode Additive Phase Jitter, Bypass Mode		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.9	1.4	3	ps (rms)	1,2,3,5
Phase Jitter PLL Mode	^L jphPCleG2	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.1	2.6	3.1	ps (rms)	1,2,3,5
PARAMETER	1,2,3,5							
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			0.5	0.6	0.7		1,2,3,5
	t _{iphPCleG1}	PCle Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
Additive Phase Jitter,				0.1	0.5	N/A		1,2,3,4, 5
	^L jphPCleG2	ŭ		0.1	0.7	N/A	•	1,2,3,4
*	t _{jphPCleG3}			0.2	0.3	N/A		1,2,3,4
Бурасо Мосо	t _{jph125M0}	,		200	250	N/A		1,6
	t _{jph125M1}	125MHz, 12KHz to 20MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		313	350	N/A	fs (rms)	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

⁴ All outputs at default slew rate

⁵ The MIN/TYP/MAX values of each BW setting track each other, i.e., Low BW MAX will never occur with Hi BW MIN.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

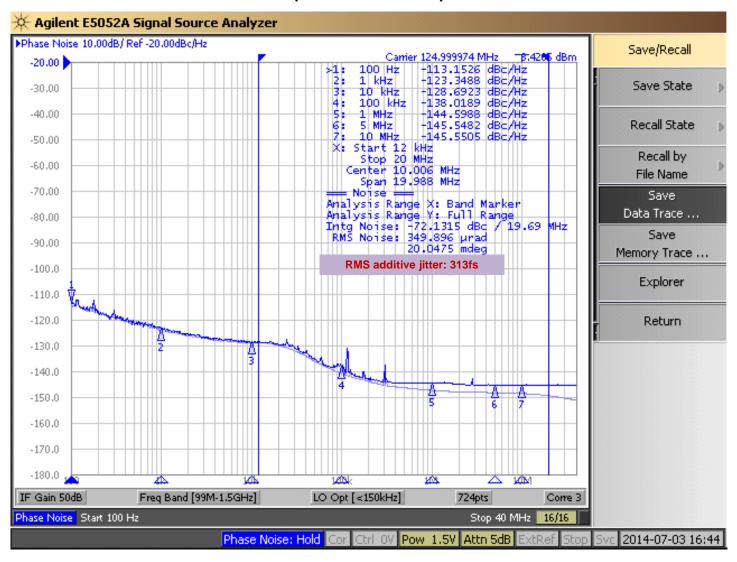
⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]

⁵ Driven by 9FGU0831 or equivalent

⁶ Rohde&Schartz SMA100



Additive Phase Jitter Plot: 125M (12kHz to 20MHz)





General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock '	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		.e	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus Address is Latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ē	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Type	0	1	Default
Bit 7	DIF OE7	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 5	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 4	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	Enabled	1

^{1.} A low on these bits will overide the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7	PLLMODERB1	PLL Mode Readback Bit 1	R	See PLL Operating Mode Table		Latch
Bit 6	PLLMODERB0	PLL Mode Readback Bit 0	R			Latch
Bit 5	PLLMODE SWCNTRL	Enable SW control of PLL Mode	RW	Values in B1[7:6]	Values in B1[4:3]	0
טונ ס	T LEWIODE_SWENTKE	Lilable 3W control of 1 EL Wode	1744	set PLL Mode	set PLL Mode	U
Bit 4	PLLMODE1	PLL Mode Control Bit 1	RW ¹	See PLL Operating Mode Table		0
Bit 3	PLLMODE0	PLL Mode Control Bit 0	RW ¹	See FLL Opera	ing wode rable	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.55V	01= 0.65V	1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10 = 0.7V	11 = 0.8V	0

^{1.} B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7	SLEWRATESEL DIF7	Adjust Slew Rate of DIF7	RW	Slow Setting	Fast Setting	1
Bit 6	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow Setting	Fast Setting	1
Bit 5	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow Setting	Fast Setting	1
Bit 4	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow Setting	Fast Setting	1
Bit 3	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow Setting	Fast Setting	1
Bit 2	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow Setting	Fast Setting	1
Bit 1	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1

Note: See "Low-Power HCSL Outputs" table for slew rates.

SMBus Table: Frequency Select Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7	Reserved					
Bit 6	Reserved					
Bit 5		Reserved				0
Bit 4	Reserved					
Bit 3		Reserved				0
Bit 2		Reserved				1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL FB	Adjust Slew Rate of FB	RW	Slow Setting	Fast Setting	1

Byte 4 is Reserved and reads back 'hFF



SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default	
Bit 7	RID3	R			0		
Bit 6	RID2	Revision ID	R	Λ rov -	A rev = 0000		
Bit 5	RID1	IVEAISION ID	R	A lev =	0		
Bit 4	RID0		R		0		
Bit 3	VID3		R			0	
Bit 2	VID2	VENDOR ID	R	0001	0001 = IDT		
Bit 1	VID1	VENDOR ID	R	1 0001 = 101		0	
Bit 0	VID0		R			1	

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx, 01 =	0	
Bit 6	Device Type0	Device Type	R	10 = DMx, 1	1	
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R		0	
Bit 3	Device ID3	Device ID	R	001000 bina	00 binary or 08 hex	
Bit 2	Device ID2	Device ID	R	00 1000 billa		
Bit 1	Device ID1		R			0
Bit 0	Device ID0		R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				0
Bit 6		Reserved				0
Bit 5		Reserved				0
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	er will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0



Marking Diagrams

ICS
DBU0841AL
YYWW
COO
LOT



Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. YYWW is the last two digits of the year and week that the part was assembled.
- 4. Line 2: truncated part number
- 5. "L" denotes RoHS compliant package.
- 6. "I" denotes industrial temperature range device.

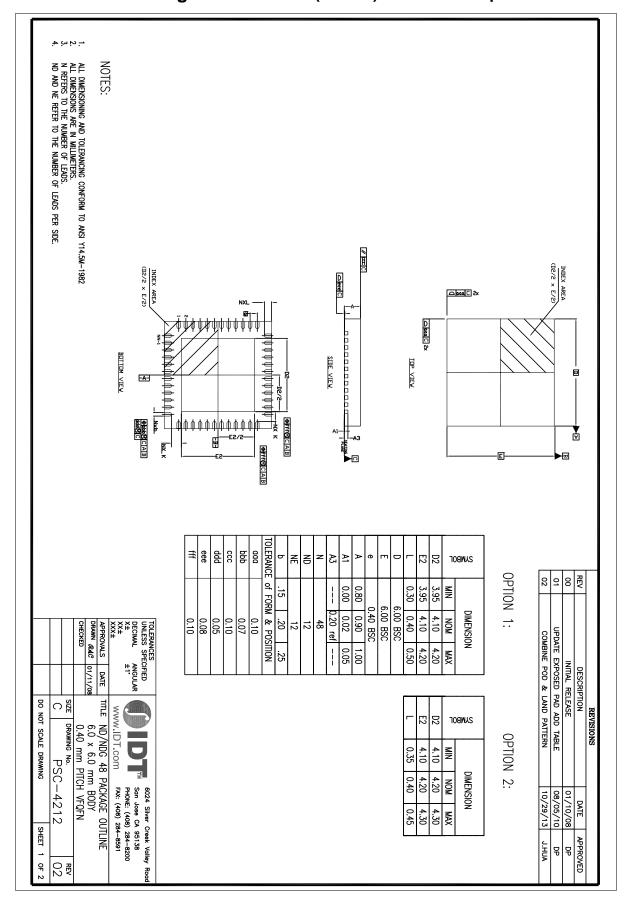
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	θ_{JC}	Junction to Case		33	°C/W	1
	θ_{Jb}	Junction to Base		2.1	°C/W	1
Thermal Resistance	$\theta_{JA0\theta}$	Junction to Air, still air	NDG48 37 30		°C/W	1
memai nesistance	θ_{JA1}	Junction to Air, 1 m/s air flow			°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		27	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		26	°C/W	1

¹ePad soldered to board

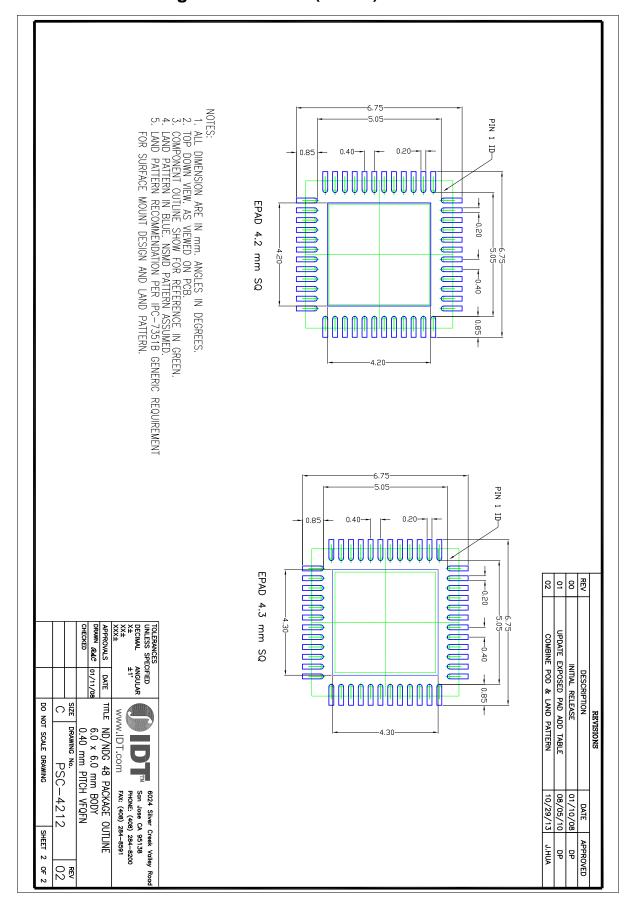


Package Outline and Package Dimensions (NDG48) - use EPAD Option 1





Package Outline and Package Dimensions (NDG48) - use EPAD 4.2 mm SQ





Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBU0841AKLF	Trays	48-pin VFQFPN	0 to +70° C
9DBU0841AKLFT	Tape and Reel	48-pin VFQFPN	0 to +70° C
9DBU0841AKILF	Trays	48-pin VFQFPN	-40 to +85° C
9DBU0841AKILFT	Tape and Reel	48-pin VFQFPN	-40 to +85° C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History

Rev.	Initiator	Issue Date	Description	Page #	
A F		7/16/2014	Updated electrical tables with char data.		
	RDW		2. Added an additive phase jitter plot.	Various	
	NUVV		3. Added 12kHz to 20MHz additive phase jitter spec.		
			4. Updated Amplitude control bit descriptions in Byte 1.		
B RDW	DDW	9/19/2014	Updated SMBus Input High/Low parameters conditions, MAX values, and	6	
	9/19/2014	footnotes.	0		
С	RDW	4/17/2015	Updated pin out and pin descriptions to show ePad on package		
			connected to ground.		
			Minor updates to front page text for family consistency.	1-6	
			3. Updated Clock Input Parameters table to be consistent with PCIe		
			Vswing parameter.		

[&]quot;A" is the device revision designator (will not correlate with the datasheet revision).



Corporate Headquarters 6024 Silver Creek Valley Road San Jose, CA 95138 USA

Sales

1-800-345-7015 or 408-284-8200 Fax: 408-284-2775

www.IDT.com

Tech Support

email: clocks@idt.com

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